

*WPA
6/24/02*

DOCKET NO. MICHEJDA 4-6

PATENT

*#P/A
Product
J. Michejda
2/4/03*

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

John A. Michejda, et al.

Serial No.: 09/882,911

Filed: June 15, 2001

For: A SEMICONDUCTOR DEVICE HAVING A GHOST SOURCE DRAIN REGION AND A METHOD OF MANUFACTURE THEREFOR

Group No.: 2815

Examiner: Fenty, Jesse A.

Honorable Commissioner of Patents
Washington, D.C. 20231*I hereby certify that one copy of this paper is being deposited with the United States Postal Service as first class mail in an envelope addressed to: "Commissioner of Patents and Trademarks, Washington, D.C. 20231" on 6/24/02.**Glenn D. Schumacher
Glenn D. Schumacher
(Signature of the person depositing the paper)
(Signature of the person signing the certificate)*

Sir:

AMENDMENT UNDER 37 C.F.R. § 1.111

In response to the Examiner's Action mailed March 14, 2002, please amend the above-identified application as follows:

FAX RECEIVED

IN THE CLAIMS:

JAN 30 2003

(1) Kindly rewrite Claim 1 as follows:

TECHNOLOGY CENTER 2800

1. (Amended) A semiconductor device, comprising:
 a channel region located in a semiconductor substrate;
 a trench located adjacent a side of the channel region;

A 1